

74LVC2G14 Dual Inverter with 5V Tolerant Schmitt Trigger Inputs

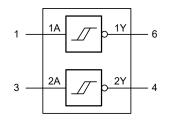
GENERAL DESCRIPTION

The 74LVC2G14 contains two independent inverters each with Schmitt trigger input. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals. The 74LVC2G14 is designed for 1.65V to 5.5V V_{CC} operation. The device performs the Boolean function $Y = \overline{A}$.

Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of this device in a mixed 3.3V and 5V environment. Schmitt trigger action at the inputs makes the circuit tolerant of slower input rise and fall times.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

LOGIC SYMBOL



FEATURES

- Wide Supply Voltage Range: 1.65V to 5.5V
- 5V Tolerant Inputs for Interfacing with 5V Logic
- High Noise Immunity
- ±24mA Output Drive at V_{cc} = 3.0V
- CMOS Low Power Consumption
- Direct Interface with TTL Levels
- Unlimited Rise and Fall Times
- Inputs Accept Voltages up to 5V
- -40°C to +125°C Operating Temperature Range
- Available in a Green SC70-6 Package

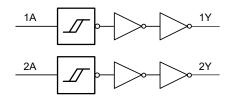
FUNCTIONAL TABLE

INPUT	OUTPUT
nA	nY
L	Н
Н	L

Y = Ā

H = High Voltage Level L = Low Voltage Level

LOGIC DIAGRAM



PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION			PACKAGE MARKING	PACKING OPTION
74LVC2G14	SC70-6	-40°C to +125°C	74LVC2G14XC6G/TR	R55XX	Tape and Reel, 3000

MARKING INFORMATION

NOTE: XX = Date Code.

YYY X X Date Code - Week Date Code - Year

— Serial Number

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS (1)

Supply Voltage, V _{CC} 0.5V to 6.5V
Input Voltage, VI ⁽²⁾ 0.5V to 6.5V
Output Voltage, V _O ⁽²⁾
Active Mode0.5V to V_{CC} +0.5V
Power-Down Mode, V _{CC} = 0V0.5V to 6.5V
Input Clamping Current, I _{IK} (V _I < 0V)50mA
Output Clamping Current, I_{OK} (V _O > V _{CC} or V _O < 0V)
±50mA
Output Current, I_O (V _O = 0V to V _{CC}) ±50mA
Supply Current, I _{CC} 100mA
Ground Current, I _{GND} 100mA
Junction Temperature ⁽³⁾ +150°C
Storage Temperature Range65°C to +150°C
Lead Temperature (Soldering, 10s)+260°C
ESD Susceptibility
HBM
CDM

RECOMMENDED OPERATING CONDITIONS

Supply Voltage, V _{CC}	1.65V to 5.5V
Input Voltage, V _I	0V to 5.5V
Output Voltage, V _O	
Active Mode	$0V$ to V_{CC}
Power-Down Mode, V _{CC} = 0V	0V to 5.5V
Input Transition Rise and Fall Rate, $\Delta t/\Delta V$	
V _{CC} = 1.65V to 2.7V	20ns/V (MAX)
V _{CC} = 2.7V to 5.5V	10ns/V (MAX)
Operating Temperature Range	40°C to +125°C

OVERSTRESS CAUTION

1. Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

2. The input and output voltage ratings may be exceeded if the input and output clamp current ratings are observed.

3. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

ESD SENSITIVITY CAUTION

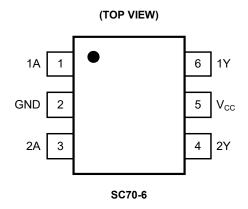
This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.



PIN CONFIGURATION



PIN DESCRIPTION

PIN	NAME	FUNCTION
1, 3	1A, 2A	Data Inputs.
2	GND	Ground.
4, 6	2Y, 1Y	Data Outputs.
5	Vcc	Supply Voltage.



ELECTRICAL CHARACTERISTICS

(Full = -40°C to +125°C. All typical values are measured at maximum V_{CC} and T_A = +25°C, unless stated noted.)

PARAMETER	SYMBOL		CONDITIONS	TEMP	MIN	TYP	MAX	UNITS
			I_0 = -100µA, V_{CC} = 1.65V to 5.5V	Full	V _{CC} - 0.05	V _{cc} - 0.01		
			I _o = -4mA, V _{CC} = 1.65V	Full	1.43	1.55		
	M	$\lambda = \lambda = \lambda$	I _o = -8mA, V _{CC} = 2.3V	Full	2.02	2.18		
High-Level Output Voltage	V _{он}	$V_I = V_{T^+} \text{ or } V_{T^-}$	I _o = -12mA, V _{CC} = 2.7V	Full	2.38	2.56		V
			I _o = -24mA, V _{CC} = 3V	Full	2.52	2.74		
			I _o = -32mA, V _{CC} = 4.5V	Full	4	4.22		
			I_0 = 100µA, V_{CC} = 1.65V to 5.5V	Full		0.01	0.05	
			I _o = 4mA, V _{CC} = 1.65V	Full		0.1	0.22	V
	N/	$V_1 = V_{T^+}$ or V_{T^-}	I _o = 8mA, V _{CC} = 2.3V	Full		0.12	0.28	
Low-Level Output Voltage	V _{OL}		I _o = 12mA, V _{CC} = 2.7V	Full		0.16	0.34	v
			I _o = 24mA, V _{CC} = 3V	Full		0.3	0.56	
			I _o = 32mA, V _{CC} = 4.5V	Full		0.32	0.6	
Input Leakage Current	I _I	V _I = 5.5V or G	ND, V_{CC} = 0V to 5.5V	Full		±0.01	±1	μA
Power-Off Leakage Current	I _{OFF}	$V_1 \text{ or } V_0 = 5.5 $	$V_1 \text{ or } V_0 = 5.5 \text{V}, V_{CC} = 0 \text{V}$			±0.01	±1	μA
Supply Current	I _{cc}	V_1 = 5.5V or GND, V_{CC} = 1.65V to 5.5V, I_0 = 0A		Full		0.01	1	μA
Additional Supply Current ⁽¹⁾	ΔI_{CC}	$V_1 = V_{CC} - 0.6V, I_0 = 0A, V_{CC} = 2.3V \text{ to } 5.5V$		Full		0.05	10	μA
Input Capacitance	Cı	V_{CC} = 3.3V, V_{I}	= GND to V _{CC}	+25 ℃		3		pF

NOTE:

1. This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND.

DYNAMIC CHARACTERISTICS

(For test circuit, see Figure 4. All typical values are measured at T_A = +25°C and V_{CC} = 1.8V, 2.5V, 2.7V, 3.3V and 5V respectively, unless stated noted.)

PARAMETER	SYMBOL	CONDITIONS		TEMP	MIN	TYP	MAX	UNITS
Propagation Delay ⁽²⁾			V _{CC} = 1.65V to 1.95V	+25 ℃		10.1		
			V_{CC} = 2.3V to 2.7V	+25 ℃		5.6		
	t _{PD}	nA to nY, see Figure 5	V _{CC} = 2.7V	+25 ℃		5.2		ns
		eee rigare e	V_{CC} = 3V to 3.6V	+25 ℃		5.2		
			V _{CC} = 4.5V to 5.5V	+25 ℃		4.4		
Power Dissipation Capacitance (3)	CPD	V_i = GND to V_{cc}	c, V _{CC} = 3.3V	+25 ℃		40		pF

NOTES:

2. t_{PD} is the same as t_{PLH} and t_{PHL} .

3. C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o})$ where:

 f_i = Input frequency in MHz. f_o = Output frequency in MHz.

C_L = Output load capacitance in pF.

V_{CC} = Supply voltage in Volts.

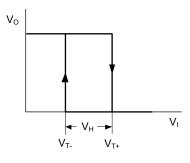
N = Number of inputs switching.

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = Sum of outputs.

TRANSFER CHARACTERISTICS

(Full = -40°C to +125°C. All typical values are measured at T_A = +25°C, unless stated noted.)

PARAMETER	SYMBOL	С	ONDITIONS	TEMP	MIN	TYP	MAX	UNITS	
			V _{CC} = 1.8V	Full	0.7	1.1	1.7		
			V _{CC} = 2.3V	Full	1	1.4	2	V	
Positive-Going Threshold Voltage	V _{T+}	See Figure 1 and Figure 2	V_{CC} = 3V, see Figure 3	Full	1.3	1.76	2.4	V	
		and right b	V _{CC} = 4.5V	Full	1.9	2.47	3.3		
			V _{CC} = 5.5V	Full	2.2	2.91	3.8		
			V _{CC} = 1.8V	Full	0.25	0.61	1.1		
			V _{CC} = 2.3V	Full	0.4	0.8	1.35		
Negative-Going Threshold Voltage	V _{T-}	See Figure 1 and Figure 2	V _{CC} = 3V, see Figure 3	Full	0.6	1.04	1.7	V	
			V _{CC} = 4.5V	Full	1	1.55	2.2		
			V _{CC} = 5.5V	Full	1.2	1.86	2.5		
			V _{CC} = 1.8V	Full	0.15	0.49	1.2		
		(V _{T+} - V _{T-}),	V _{CC} = 2.3V	Full	0.25	0.6	1.3		
Hysteresis Voltage	V _H	See Figure 1	V _{CC} = 3V, see Figure 3	Full	0.4	0.73	1.4	V	
		and Figure 2	V _{CC} = 4.5V	Full	0.6	0.92	1.7		
			V _{CC} = 5.5V	Full	0.7	1.02	1.9	1	





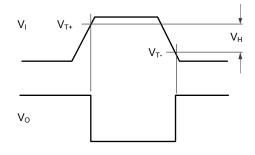


Figure 2. Definition of $V_{T^+},\,V_{T^-}\,and\,V_H$

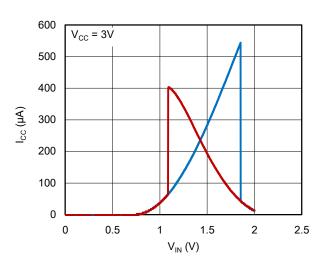
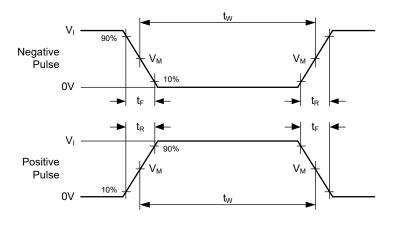


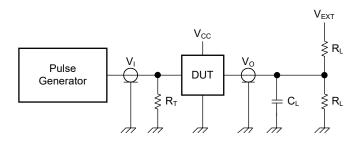
Figure 3. Typical Transfer Characteristics



74LVC2G14

TEST CIRCUIT





Test conditions are given in Table 1.

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Zo of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Figure 4. Test Circuit for Measuring Switching Times

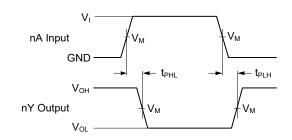
Table 1. Test Conditions

SUPPLY VOLTAGE	INPUT		LC	V _{EXT}	
Vcc	Vi	t _R = t _F	C∟	RL	t _{PLH} , t _{PHL}
1.65V to 1.95V	V _{CC}	≤ 2.0ns	30pF	1kΩ	Open
2.3V to 2.7V	V _{CC}	≤ 2.0ns	30pF	500Ω	Open
2.7V	2.7V	≤ 2.5ns	50pF	500Ω	Open
3.0V to 3.6V	2.7V	≤ 2.5ns	50pF	500Ω	Open
4.5V to 5.5V	V _{CC}	≤ 2.5ns	50pF	500Ω	Open



74LVC2G14

WAVEFORMS



Test conditions are given in Table 1.

Measurement points are given in Table 2.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Figure 5. The Data Input (nA) to Output (nY) Propagation Delays

Table 2. Measurement Points

SUPPLY VOLTAGE	INPUT	OUTPUT
Vcc	V _M	V _M
1.65V to 1.95V	0.5 × V _{CC}	$0.5 \times V_{CC}$
2.3V to 2.7V	0.5 × V _{CC}	$0.5 \times V_{CC}$
2.7V	1.5V	1.5V
3.0V to 3.6V	1.5V	1.5V
4.5V to 5.5V	0.5 × V _{CC}	$0.5 \times V_{CC}$

REVISION HISTORY

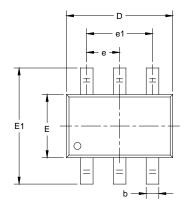
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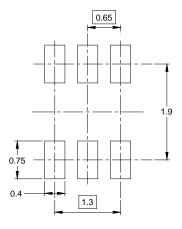
Changes from Original (FEBRUARY 2021) to REV.A	Page
Changed from product preview to production data	All



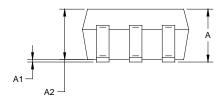
PACKAGE OUTLINE DIMENSIONS

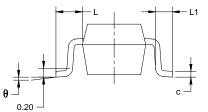
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RECOMMENDED LAND PATTERN (Unit: mm)

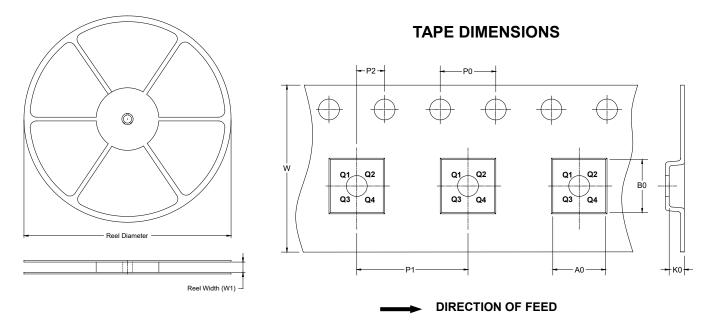




Symbol	-	nsions meters	-	nsions ches	
	MIN	MAX	MIN	MAX	
A	0.800	1.100	0.031	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.800	1.000	0.031	0.039	
b	0.150	0.350	0.006	0.014	
С	0.080	0.220	0.003	0.009	
D	2.000	2.200	0.079	0.087	
E	1.150	1.350	0.045	0.053	
E1	2.150	2.450	0.085	0.096	
е	0.65	TYP	0.026	6 TYP	
e1	1.300 BSC		0.051 BSC		
L	0.525	0.525 REF		REF	
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	

TAPE AND REEL INFORMATION

REEL DIMENSIONS

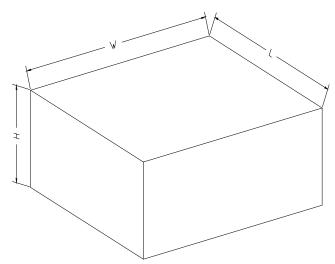


NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SC70-6	7″	9.5	2.40	2.50	1.20	4.0	4.0	2.0	8.0	Q3

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton	
7" (Option)	368	227	224	8	
7"	442	410	224	18	00002



单击下面可查看定价,库存,交付和生命周期等信息

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